

SDS52BF THRU SDS520BF

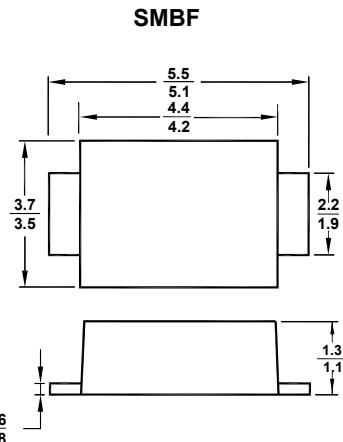
Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 20 to 200 V

Forward Current - 5 A

Features

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications



All Dimensions in mm

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	Symbols	SDS52BF	SDS54BF	SDS56BF	SDS58BF	SDS510BF	SDS512BF	SDS515BF	SDS520BF	Unit
Marking		S52B	S54B	S56B	S58B	S510B	S512B	S515B	S520B	-
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	20	40	60	80	100	120	150	200	V
Maximum RMS Voltage	V _{RMS}	14	28	42	56	70	84	105	140	V
Maximum DC Blocking Voltage	V _{DC}	20	40	60	80	100	120	150	200	V
Maximum Average Forward Rectified Current	I _{F(AV)}	5							A	
Peak Forward Surge Current 8.3 ms Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	150							A	
Maximum Instantaneous Forward Voltage at 5 A	V _F	0.55	0.7			0.85				V
Maximum DC Reverse Current at T _a = 25°C Rated DC Blocking Voltage T _a = 100°C	I _R	1 50								mA
Typical Junction Capacitance ¹⁾	C _j	800		500						pF
Typical Thermal Resistance ²⁾	R _{θJA}			45						°C/W
Operating Junction Temperature Range	T _j				- 55 to + 125					°C
Storage Temperature Range	T _{stg}					- 55 to + 150				°C

¹⁾ Measured at 1MHz and applied reverse voltage of 4 V D.C.

²⁾ P.C.B. mounted with 0.5 X 0.5" (12.7 X 12.7 mm) copper pad areas.

TOP DYNAMIC



ISO14001 : 2004

Certificate No. 121505007

ISO 9001 : 2008

Certificate No. 50114012

OHSAS 18001 : 2007

Certificate No. 0515160008

IECC Q/C 080000

Certificate No. EKH/HQ007/HQ02

Dated: 19/11/2015 JD Rev:02

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Fig.1 Forward Current Derating Curve

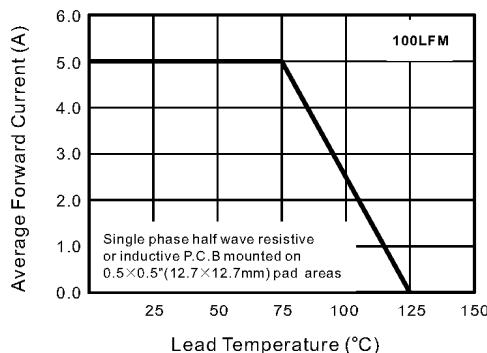


Fig.2 Typical Reverse Characteristics

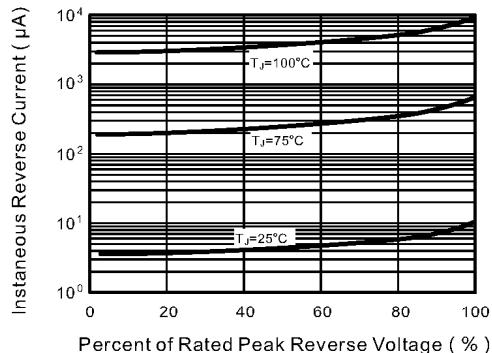


Fig.3 Typical Forward Characteristic

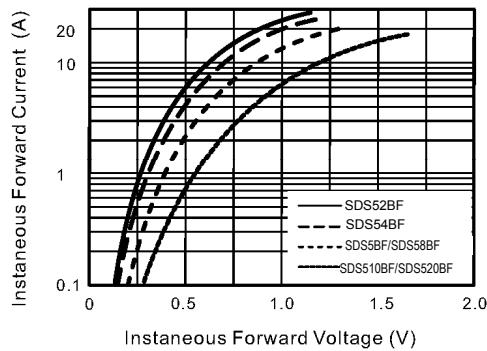


Fig.4 Typical Junction Capacitance

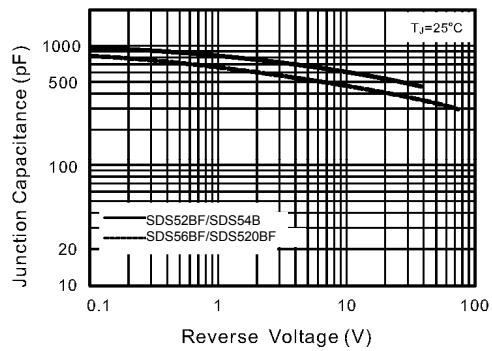


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

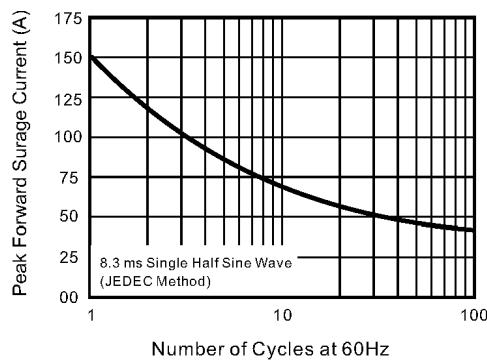
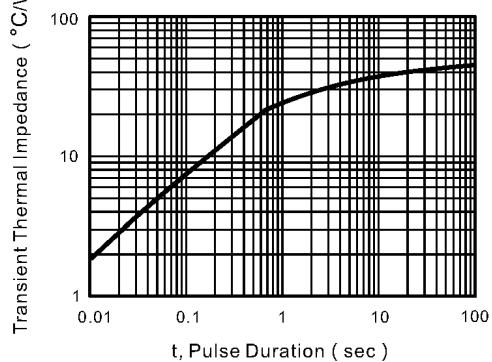


Fig.6- Typical Transient Thermal Impedance



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